

1S1585

HIGH SPEED SWITCHING DIODE

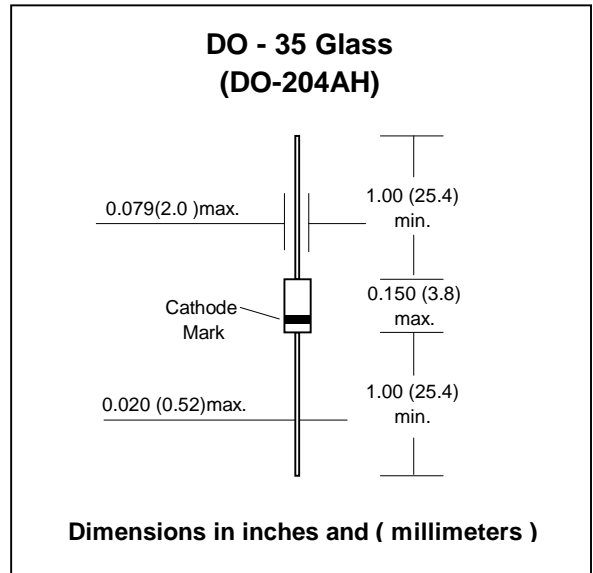
FEATURES :

- High switching speed: max. 2 ns
- Continuous reverse voltage: max. 80 V
- Repetitive peak reverse voltage: max. 90 V
- Pb / RoHS Free

MECHANICAL DATA :

Case: DO-35 Glass Case

Weight: approx. 0.13g



Maximum Ratings and Thermal Characteristics (Rating at 25 °C ambient temperature unless otherwise specified.)

Parameter	Symbol	Value	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	90	V
Maximum Continuous Reverse Voltage	V_{RM}	80	V
Maximum Continuous Forward Current	I_F	150	mA
Maximum Forward Current	I_{FM}	480	mA
Maximum Power Dissipation	P_D	300	mW
Maximum Non-repetitive Peak Forward Current	I_{FSM}	0.7	A
Maximum Junction Temperature	T_J	175	°C
Storage Temperature Range	T_S	-65 to + 200	°C

Electrical Characteristics ($T_J = 25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Current	I_R	$V_R = 80\text{ V}$	-	-	0.5	μA
Forward Voltage	V_F	$I_F = 100\text{ mA}$	-	-	1.0	V
Diode Capacitance	C_d	$f = 1\text{ MHz} ; V_R = 0$	-	-	2.0	pF
Reverse Recovery Time	T_{rr}	$I_F = 10\text{ mA to } I_R = 60\text{ mA}$ $R_L = 100\ \Omega ;$ measured at $I_R = 1\text{ mA}$	-	-	2	ns